Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Vishay Semiconductor/Opto Division</u> <u>BPW41N</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Vishay Semiconductor/Opto Division: Excellent Integrated System Limited Datasheet of BPW41N - PHOTODIODE PIN FLAT SIDE VIEW

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DESCRIPTION

900 nm to 950 nm IR emitters.

www.vishay.com

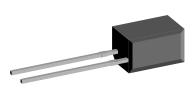
BPW41N

GREEN

(5-2008)

Vishay Semiconductors

Silicon PIN Photodiode



BPW41N is a PIN photodiode with high speed and high

radiant sensitivity in a black, side view plastic package with

daylight blocking filter. Filter bandwidth is matched with

94 8480

FEATURES

• Package type: leaded

• Package form: side view

• Dimensions (in mm): 5 x 4 x 6.8

• Radiant sensitive area (in mm²): 7.5

· High radiant sensitivity

Daylight blocking filter matched with 940 nm emitters

Fast response times

• Angle of half sensitivity: $\varphi = \pm 65^{\circ}$

 Compliant to RoHS Directive to 2002/95/EC and in accordance to WEEE 2002/96/EC

Note

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

APPLICATIONS

- · High speed detector for infrared radiation
- Infrared remote control and free air data transmission systems, e.g. in combination with TSALxxxx series IR emitters

PRODUCT SUMMARY COMPONENT I_{ra} (μA) φ (deg) $λ_{0.5}$ (nm) BPW41N 45 ± 65 870 to 1050

Note

• Test condition see table "Basic Characteristics"

ORDERING INFORMATION						
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM			
BPW41N	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	Side view			

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Reverse voltage		V _R	60	V			
Power dissipation	T _{amb} ≤ 25 °C	P _V	215	mW			
Junction temperature		Tj	100	°C			
Operating temperature range		T _{amb}	- 40 to + 100	°C			
Storage temperature range		T _{stg}	- 40 to + 100	°C			
Soldering temperature	t ≤ 5 s	T _{sd}	260	°C			
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm ²	R _{thJA}	350	K/W			

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BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Breakdown voltage	I _R = 100 μA, E = 0	V _(BR)	60			V	
Reverse dark current	V _R = 10 V, E = 0	I _{ro}		2	30	nA	
Diode capacitance	V _R = 0 V, f = 1 MHz, E = 0	C _D		70		pF	
	V _R = 3 V, f = 1 MHz, E = 0	C _D		25	40	pF	
Open circuit Voltage	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$	Vo		350		mV	
Temperature coefficient of Vo	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$	TK _{Vo}		- 2.6		mV/K	
Short circuit current	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$	I _k		38		μΑ	
Temperature coefficient of I _k	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$	TK _{Ik}		0.1		%/K	
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm},$ $V_R = 5 \text{ V}$	I _{ra}	43	45		μΑ	
Angle of half sensitivity		φ		± 65		deg	
Wavelength of peak sensitivity		λ_{p}		950		nm	
Range of spectral bandwidth		λ _{0.5}		870 to 1050		nm	
Noise equivalent power	$V_R = 10 \text{ V}, \lambda = 950 \text{ nm}$	NEP		4 x 10 ⁻¹⁴		W/√ Hz	
Rise time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t _r		100		ns	
Fall time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t _f		100		ns	

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

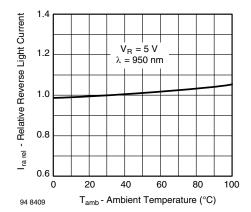


Fig. 1 - Relative Reverse Light Current vs. Ambient Temperature

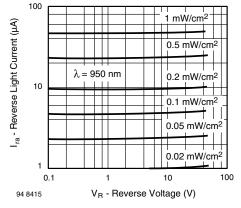


Fig. 3 - Reverse Light Current vs. Reverse Voltage

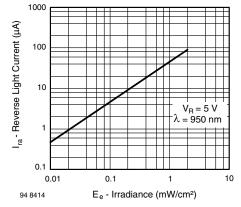


Fig. 2 - Reverse Light Current vs. Irradiance

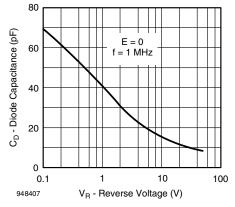


Fig. 4 - Diode Capacitance vs. Reverse Voltage

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Datasheet of BPW41N - PHOTODIODE PIN FLAT SIDE VIEW

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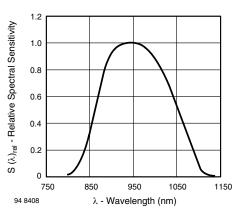


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength

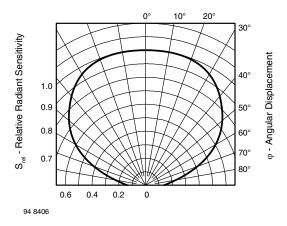
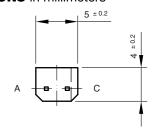
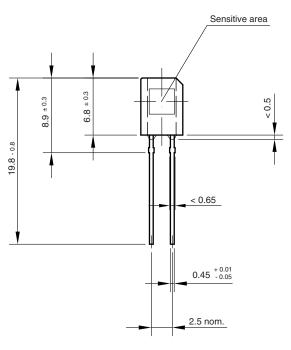


Fig. 6 - Relative Radiant Sensitivity vs. Angular Displacement

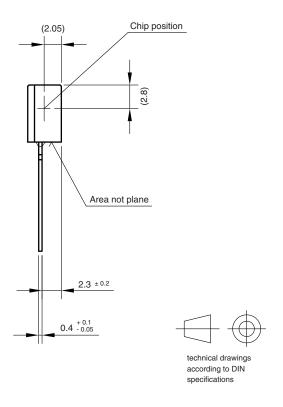
PACKAGE DIMENSIONS in millimeters







96 12195



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